TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7SZU04AFE

Inverter

Features

• High output drive: ±16 mA (typ.)

$$@VCC = 3 V$$

Low quiescent power: I_{CC} < 2 μA (max)

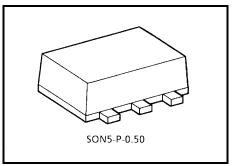
$$@V_{CC} = 5.5 \text{ V}, \text{ Ta} = 25^{\circ}\text{C}$$

• Operation voltage range: $V_{CC (opr)} = 1.8 \sim 5.5 \text{ V}$

• Supply voltage data retention: $V_{CC} = 1.5 \sim 5.5 \text{ V}$

• Latch-up performance: ±500 mA

• Power down protection is provided on all inputs.



Weight: 0.003 g (typ.)

Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~6	V
DC input voltage	V _{IN}	-0.5~6	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V
Input diode current	I _{IK}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±50	mA
DC V _{CC} /ground current	Icc	±50	mA
Power dissipation	PD	150	mW
Storage temperature	T _{stg}	-65~150	°C
Lead temperature (10 s)	TL	260	°C



Electrical Characteristics

DC Characteristics

Characteristics Symbol	Test	Test Condition			Ta = 25°C			Ta = -40~85°C			
	Circuit			V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit	
High-level input voltage		_		1.8	0.85 × V _{CC}	_	_	0.85 × V _{CC}		- v	
				2.3- 5.5	0.8 × V _{CC}	_	_	0.8 × V _{CC}	_		
Low-level input voltage		$V_{IN} = V_{IH}$ or V_{IL}		1.8	_	_	0.15 × V _{CC}	_	0.15 × V _{CC}	V	
	_			2.3- 5.5	_	_	0.2 × V _{CC}	_	0.2 × V _{CC}		
					1.8	1.6	1.8	-	1.6		
High-level output voltage ^V ОН		VIN = VIL	$I_{OH} = -100 \mu A$	2.3	2.1	2.3	_	2.1	_	· V	
				3.0	2.7	3.0	_	2.7	_		
	_			4.5	4.0	4.4	_	4.0	_		
		V _{IN} = GND	$I_{OH} = -4 \text{ mA}$	2.3	1.9	2.14	_	1.9			
			$I_{OH} = -8 \text{ mA}$	3.0	2.4	2.75		2.4			
			$I_{OH} = -12 \text{ mA}$	3.0	2.3	2.61		2.3			
				$I_{OH} = -16 \text{ mA}$	4.5	3.8	4.13		3.8		
					1.8	_	0	0.2	_	0.2	
Low-level output voltage		V _{IN} = V _{IH}		2.3	_	0	0.2		0.2	V	
				3.0	—	0	0.3	_	0.3		
				4.5		0	0.5		0.5		
		V _{IN} =	$I_{OL} = 4 \text{ mA}$	2.3	_	0.1	0.3		0.3		
			$I_{OL} = 8 \text{ mA}$	3.0	_	0.17	0.4		0.4		
			$I_{OL} = 12 \text{ mA}$	3.0	_	0.25	0.55		0.55		
				I _{OL} = 16 mA	4.5	_	0.26	0.55	_	0.55	
Input leakage current	I _{IN}	_	V _{IN} = 5.5 V or GND		0- 5.5	_	ı	±1	ı	±10	μА
Quiescent supply current	Icc	_	$V_{IN} = V_{CC}$ or GND		5.5	_		2		20	μА

AC Characteristics (input: $t_r = t_f = 3$ ns)

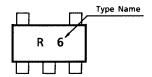
Characteristics Symbol	Test Circuit	Test Condition		Ta = 25°C			Ta = -40~85°C		Unit	
			V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic	
Propagation delay tPLH time tPHL			C _L = 15 pF,	1.8	1.0	_	8.5	1.0	9.0	ns
				2.5 ± 0.2	0.8	_	6.2	0.8	6.5	
	t _{PLH}		$R_L = 1 M\Omega$	3.3 ± 0.3	0.5	_	4.5	0.5	4.8	
	t _{PHL}			5.0 ± 0.5	0.5	_	3.9	0.5	4.1	
			C _L = 50 pF,	3.3 ± 0.3	1.0	_	6.0	1.0	6.5	
		$R_L = 500 \Omega$	5.0 ± 0.5	0.8	_	5.0	0.8	5.5		
Input capacitance	C _{IN}	_	_	0-5.5	_	5	_	_	_	pF
Power dissipation capacitance C _{PD}		(Note)	3.3	_	9	_	_	_	, F	
	CPD		(Note	5.5		25		_	_	pF

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

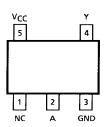
Average operating current can be obtained by the equation.

$$I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

Marking



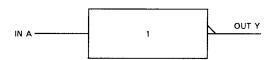
Pin Assignment (top view)



Truth Table



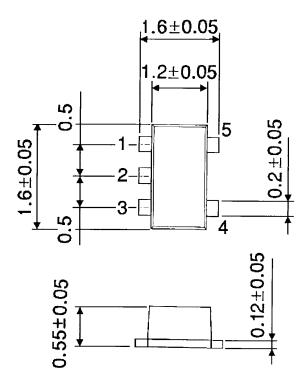
Logic Diagram



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Package Dimensions

SON5-P-0.50 Unit: mm



Weight: 0.003 g (typ.)

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